



60V P-CHANNEL ENHANCEMENT MODE MOSFET

Product Summary

BV _{DSS}	RDS(ON) Max	I _D T _A = +25°C
-60V	10Ω @ V _{GS} = -5V	-176mA

Description and Applications

This MOSFET is designed to meet the stringent requirements of automotive applications. It is qualified to AEC-Q101, supported by a PPAP, and is ideal for use in:

- General-purpose interfacing switches
- Power-management functions
- Analog switches

Features and Benefits

- Low On-Resistance
- Low Gate Threshold Voltage
- Low Input Capacitance
- Fast Switching Speed
- Low Input/Output Leakage
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- The DMP612DLQ is suitable for automotive applications requiring specific change control; this part is AEC-Q101 qualified, PPAP capable, and manufactured in IATF 16949 certified facilities.

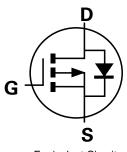
https://www.diodes.com/quality/product-definitions/

Mechanical Data

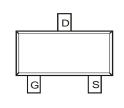
- Package: SOT23
- Package Material: UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Matte Tin Finish (Lead Free Plating) Solderable per MIL-STD-202, Method 208 (3)
- Terminal Connections: See Diagram
- Weight: 0.009 grams (Approximate)







Equivalent Circuit



Top View

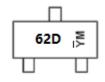
Ordering Information (Note 4)

Orderable Part Number	rderable Part Number Package		Packing		
Orderable Part Number	Package	Qty.	Carrier		
DMP612DLQ-7	SOT23	3,000	Tape & Reel		
DMP612DLQ-13	SOT23	10,000	Tape & Reel		

Notes: 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.

- 2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.

Marking Information



 $\underline{62D}$ = Product Type Marking Code \underline{YM} = Date Code Marking \underline{Y} = Year (ex: M = 2025) M = Month (ex: 6 = June)

Date Code Key

Year	2025	2026	2027	2028	2029	2030	2031	2032	2033	2034	2035	2036
Code	М	N	Р	R	S	T	U	V	W	Х	Υ	Z
Month	Jan	Feb	Mar	Apr	May	Jun	Jul	Aug	Sep	Oct	Nov	Dec



Maximum Ratings (@ T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Drain-Source Voltage	VDSS	-60	V
Gate-Source Voltage Continuous	V _{GSS}	±20	V
Drain Current (Note 5) Continuous	lD	-176	mA
Pulsed Drain Current	I _{DM}	-1.2	А

Thermal Characteristics (@ TA = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Total Power Dissipation (Note 5)	P _D	0.6	mW
Thermal Resistance, Junction to Ambient	RθJA	208	°C/W
Operating and Storage Temperature Range	T _J , T _{STG}	-55 to +150	°C

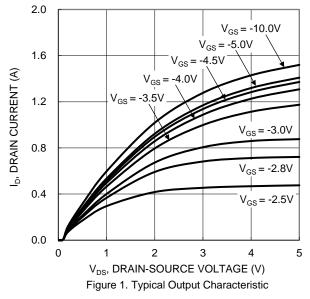
Electrical Characteristics (@ TA = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition
OFF CHARACTERISTICS (Note 6)						
Drain-Source Breakdown Voltage	BVDSS	-60	_	_	V	$V_{GS} = 0$, $I_{D} = -250\mu A$
Zero Gate Voltage Drain Current	IDSS	_	_	-1	μΑ	$V_{DS} = -60V, V_{GS} = 0$
Gate-Body Leakage	Igss	_	1	±100	nA	$V_{GS} = \pm 20V, V_{DS} = 0$
ON CHARACTERISTICS (Note 6)						
Gate Threshold Voltage	V _{GS(TH)}	-0.8	_	-2.0	V	$V_{DS} = V_{GS}$, $I_D = -250\mu A$
Static Drain-Source On-Resistance	RDS(ON)	_	1	10	Ω	V _{GS} = -5V, I _D = -100mA
Diode Forward Voltage	V_{SD}	_	-0.8	-1.5	V	$V_{GS} = 0$, $I_{S} = -100 \text{mA}$
DYNAMIC CHARACTERISTICS (Note 7)						
Input Capacitance	Ciss	_	42	_		
Output Capacitance	Coss	_	5.8		pF	$V_{DS} = -30V$, $V_{GS} = 0$, $f = 1.0MHz$
Reverse Transfer Capacitance	Crss	_	4.9	_		
Gate Resistance	Rg	_	295		Ω	$V_{DS} = 0$, $V_{GS} = 0$, $f = 1MHz$
Total Gate Charge	Qg	_	0.7	_		
Gate-Source Charge	Q_{gs}	_	0.2	_	nC	$V_{GS} = -5V$, $V_{DS} = -10V$, $I_{D} = -100$ mA
Gate-Drain Charge	Q_{gd}	_	0.2	_		
Turn-On Delay Time	tD(ON)	_	2.8	_		
Turn-On Rise Time	t _R	_	11.5	_	no	$V_{DD} = -30V, I_D = -0.27A,$
Turn-Off Delay Time	tD(OFF)	_	52.8	_	ns	$R_{GEN} = 50\Omega$, $V_{GS} = -10V$
Turn-Off Fall Time	tF	_	28.3	_		

Notes:

- 5. Device mounted on FR-4 substrate PC board, 2oz copper, with thermal bias to bottom layer 1inch square copper plate.6. Short duration pulse test used to minimize self-heating effect.7. Guaranteed by design. Not subject to production testing.





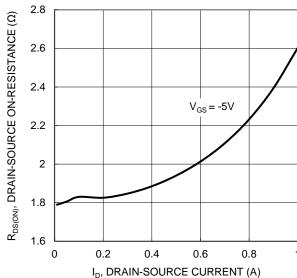


Figure 3. Typical On-Resistance vs. Drain Current and Gate Voltage

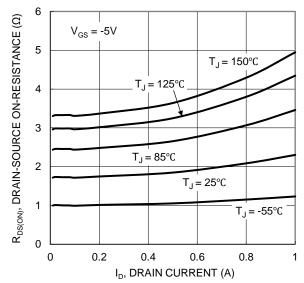
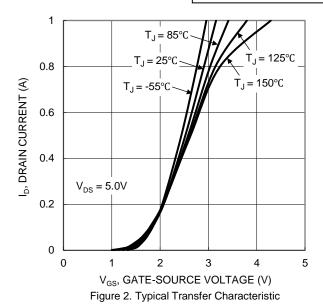
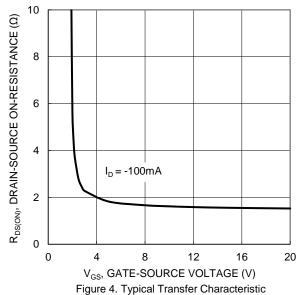


Figure 5. Typical On-Resistance vs. Drain Current and Junction Temperature





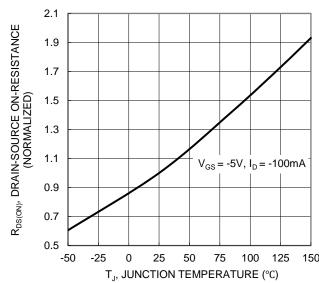


Figure 6. On-Resistance Variation with Junction Temperature





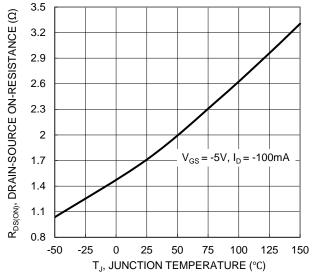


Figure 7. On-Resistance Variation with Junction Temperature

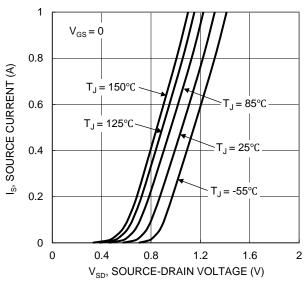


Figure 9. Diode Forward Voltage vs. Current

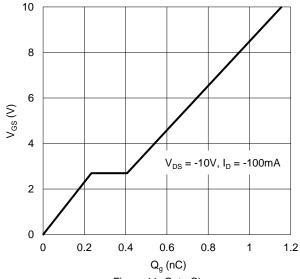


Figure 11. Gate Charge

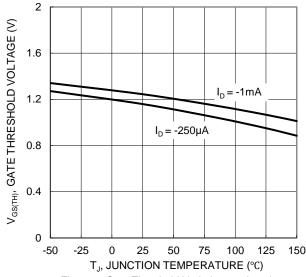


Figure 8. Gate Threshold Variation vs. Junction Temperature

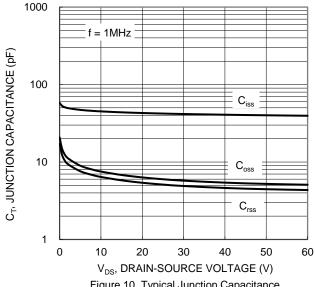


Figure 10. Typical Junction Capacitance

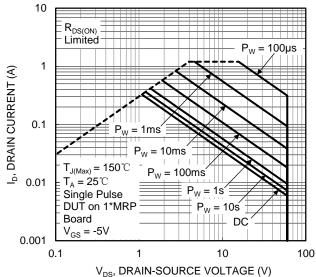


Figure 12. SOA, Safe Operation Area



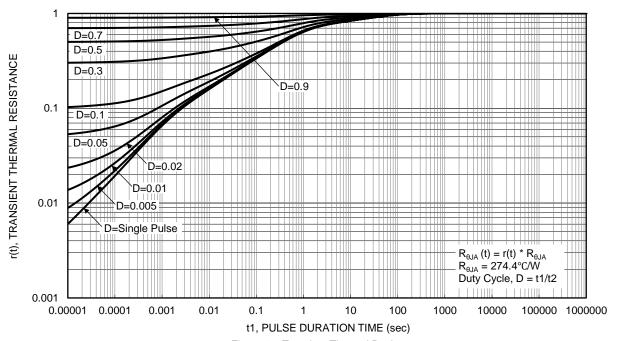


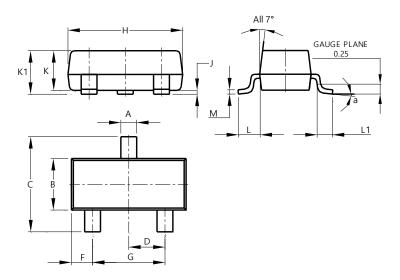
Figure 13. Transient Thermal Resistance



Package Outline Dimensions

Please see http://www.diodes.com/package-outlines.html for the latest version.

SOT23

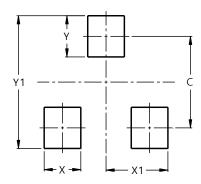


SOT23						
Dim	Min	Max	Тур			
Α	0.37	0.51	0.40			
В	1.20	1.40	1.30			
С	2.30	2.50	2.40			
D	0.89	1.03	0.915			
F	0.45	0.60	0.535			
G	1.78	2.05	1.83			
Н	2.80	3.00	2.90			
J	0.013	0.10	0.05			
K	0.890	1.00	0.975			
K1	0.903	1.10	1.025			
L	0.45	0.61	0.55			
L1	0.25	0.55	0.40			
М	0.085	0.150	0.110			
а	0°	8°				
All Dimensions in mm						

Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.

SOT23



Dimensions	Value (in mm)
O	2.0
Х	0.8
X1	1.35
Υ	0.9
Y1	29



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